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December 2013



IRLS640A N-Channel Logic Level A-FET 200 V, 9.8 A, 180 mΩ

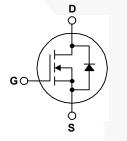
Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar, DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency switching DC/DC converters, switch mode power supplies, DC-AC converters for uninterrupted power supply and motor control.

Features

- 9.8 A, 200 V, $R_{DS(on)}$ = 180 m Ω @ V_{GS} = 5 V Low Gate Charge (Typ. 40 nC)
- Low Crss (Typ. 95 pF)
- Fast Switching
- 100% Avalanche Tested
- Improved dv/dt Capability
- Logic-Level Gate Drive





Absolute Maximum Ratings

Symbol	Characteristic	Value	Units	
V _{DSS}	Drain-to-Source Voltage	200	V	
	Continuous Drain Current (T _C =25°C)	9.8		
Ι _D	Continuous Drain Current (T _c =100℃)	6.2	A	
I _{DM}	Drain Current-Pulsed (1)	63	А	
V _{GS}	Gate-to-Source Voltage	±20	V	
E _{AS} Single Pulsed Avalanche Energy ②		64	mJ	
I _{AR}	Avalanche Current (1)	18	A	
E _{AR}	Repetitive Avalanche Energy (1)	4.0	mJ	
dv/dt	Peak Diode Recovery dv/dt 3	5	V/ns	
	Total Power Dissipation (T _c =25℃)	40	W	
P _D	Linear Derating Factor	0.32	W/℃	
	Operating Junction and	55 to 1150		
T_J , T_STG	Storage Temperature Range	- 55 to +150		
	Maximum Lead Temp. for Soldering	200	°C	
TL	Purposes, 1/8 " from case for 5-seconds	300		

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units
$R_{ extsf{ heta}JC}$	Junction-to-Case		3.13	°0111
$R_{_{ ext{ heta}JA}}$	Junction-to-Ambient		62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
IRLS640A	IRLS640A	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics (T_c =25 °C unless otherwise specified)

Symbol	Characteristic		Characteristic Min. Typ. M		Max.	Units	Test Condition
BV _{DSS}	Drain-Source Breakdown Voltage				V	V _{GS} =0V,I _D =250µA	
$\Delta \text{BV} / \Delta \text{T}_{\text{J}}$	Breakdown Voltage Temp. Coeff.		0.17		V/℃	I _D =250µA See Fig 7	
V _{GS(th)}	Gate Threshold Voltage	1.0	-	2.0	V	V _{DS} =V _{GS} , I _D =250µA	
	Gate-Source Leakage, Forward			100	nA	V _{GS} =20V	
I _{GSS}	Gate-Source Leakage, Reverse			-100		V _{GS} =-20V	
	Drain to Source Lookage Current			10		V _{DS} =200V	
I _{DSS}	Drain-to-Source Leakage Current			100	μA	V _{DS} =160V,T _C =125 ℃	
R _{DS(on)}	Static Drain-Source On-State Resistance			0.18	Ω	V _{GS} =5V,I _D =4.9A ④	
9 _{fs}	Forward Transconductance		13.3		S	V _{DS} =40V,I _D =4.9A ④	
C _{iss}	Input Capacitance		1310	1705		(1 - 0)(1) = 25)(f - 1)(1)	
C _{oss}	Output Capacitance		200	250	pF	V_{GS} =0V, V_{DS} =25V,f =1MHz	
C _{rss}	Reverse Transfer Capacitance	-	95	120		See Fig 5	
t _{d(on)}	Turn-On Delay Time		11	30			
t _r	Rise Time Turn-Off Delay Time		8	25	ns	V _{DD} =100V,I _D =18A,	
t _{d(off)}			46	100		R _G =4.6Ω	
t _f	Fall Time		15	40		See Fig 13 4 5	
Qg	Total Gate Charge		40	56		V _{DS} =160V,V _{GS} =5V,	
Q _{gs}	Gate-Source Charge		6.8		nC	I _D =18A	
Q _{gd}	Gate-Drain("Miller") Charge		18.6			See Fig 6 & Fig 12 (4) (5)	

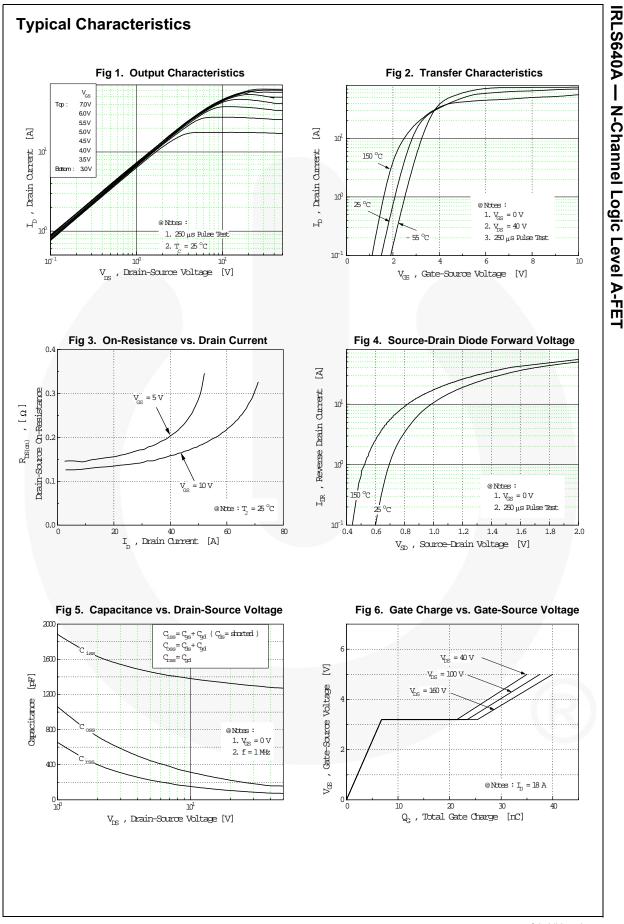
Source-Drain Diode Ratings and Characteristics

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition	
I _S	Continuous Source Current			18		Integral reverse pn-diode	
I _{SM}	Pulsed-Source Current (1)			63	A	in the MOSFET	
V _{SD}	Diode Forward Voltage ④			1.5	V	T _J =25℃,I _S =9.8A,V _{GS} =0V	
t _{rr}	Reverse Recovery Time		224		ns	T _J =25℃,I _F =18A	
Q _{rr}	Reverse Recovery Charge		1.55		μC	di _F /dt=100A/µs ④	

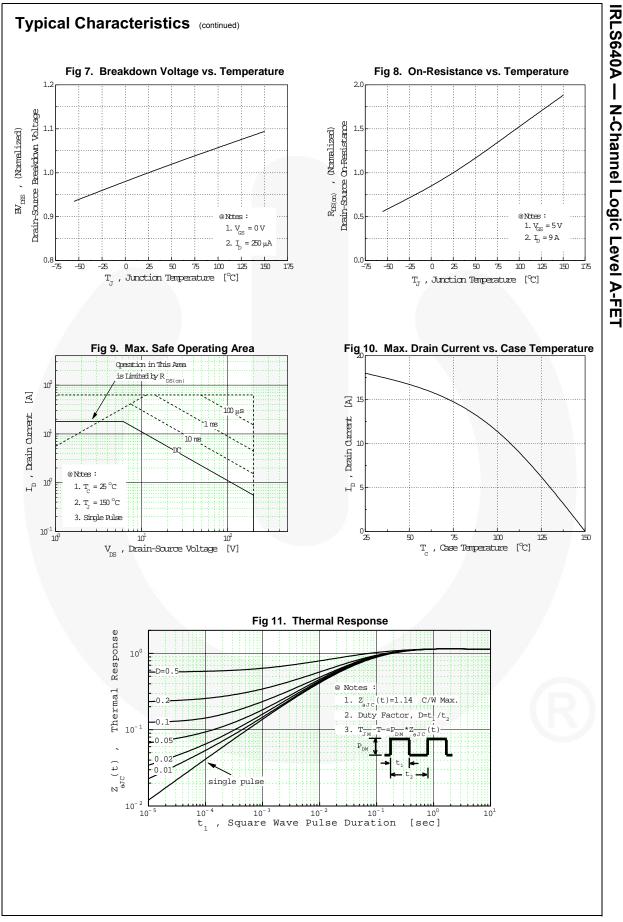
Notes :

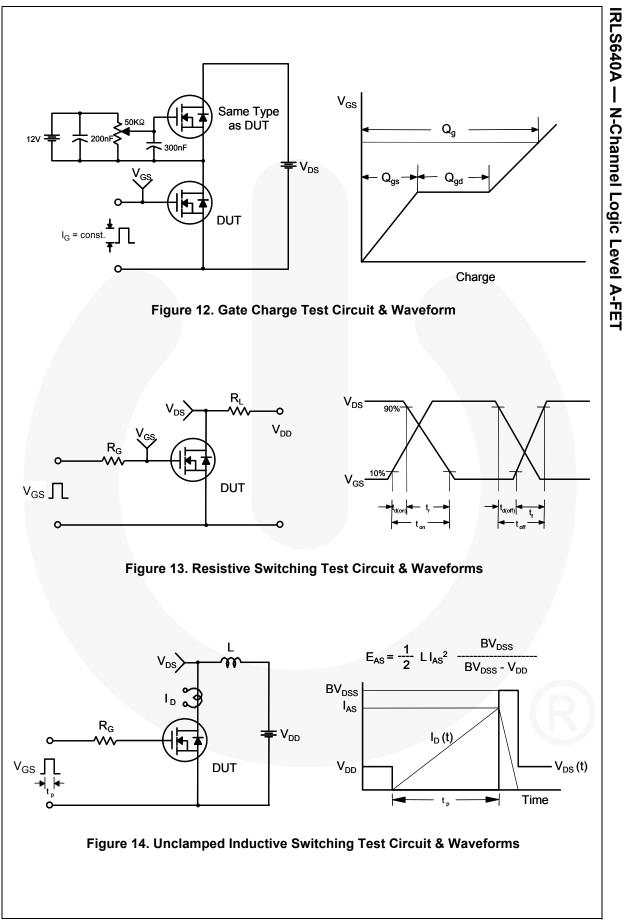
- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature

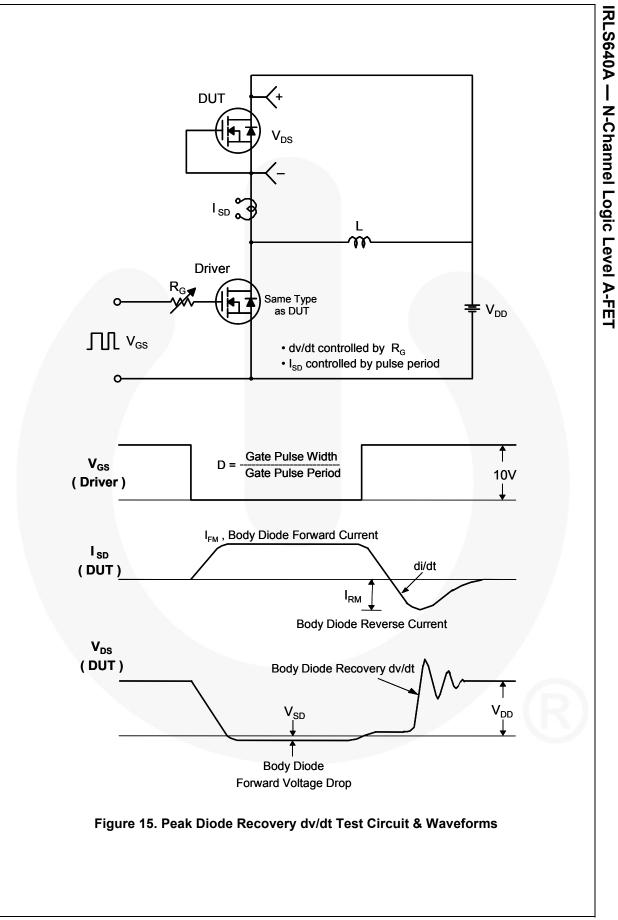
- 5 Essentially Independent of Operating Temperature

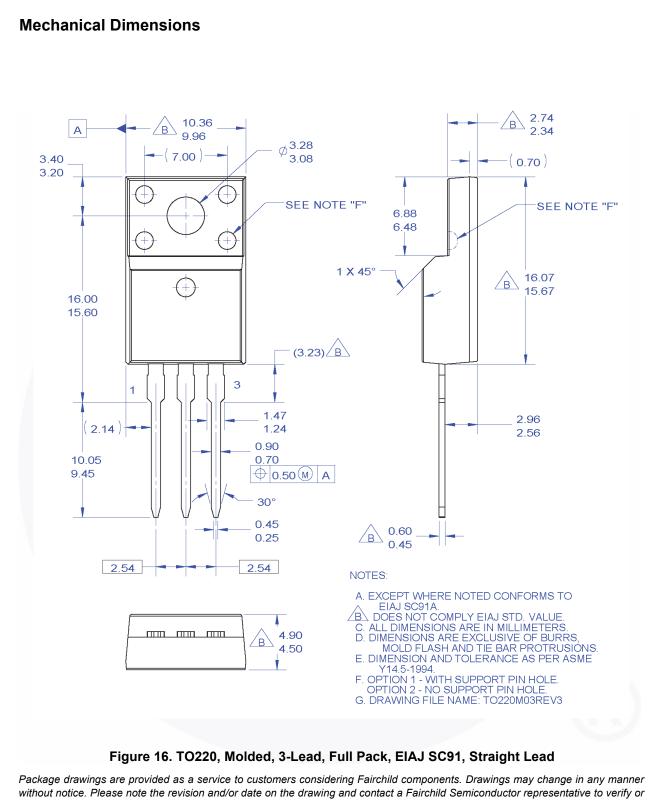


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IRLS640A —

N-Channel Logic Level A-FET



Preliminary	First Production	date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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